

AMENDMENTS TO THE SPECIFICATION AND TITLE

IN THE TITLE:

On the title page, please replace the Title with the following new Title:

NONVOLATILE SEMICONDUCTOR MEMORY DEVICE AND PROCESS
FOR PRODUCING THE SAME WITH IMPROVED GATE OXIDE FILM
ARRANGEMENT

IN THE SPECIFICATION:

On page 1, after the Title and before the heading "FIELD OF THE INVENTION," please insert the following heading and paragraph:

"CROSS-REFERENCE TO RELATED APPLICATIONS"

This application is a Continuation application of Application Serial No. 09/811,444, filed March 20, 2001, the entire disclosure of which is hereby incorporated by reference.